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Tech ID: 30169



ADDITIONAL TECHNOLOGIES BY THESE INVENTORS

- ▶ [Vertical-Stacked-Array-Transistor \(VSAT\) for Nonvolatile Memory Devices](#)
- ▶ [Magnetic Memory Bits with Perpendicular Magnetization Switched By Current-Induced Spin-Orbit Torques](#)
- ▶ [Vsat Structure for Nonvolatile Memory Device](#)
- ▶ [A Read-Disturbance-Free Nonvolatile Content Adressable Memory](#)
- ▶ [A Self-Organized Critical CMOS Circuit for Computation and Information Processing](#)
- ▶ [Anti-Ferromagnetic Magneto-Electric Spin-Orbit Read Logic](#)

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